TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC697AP,TC74HC697AF

Synchronous Presettable 4-Bit Binary Up/Down Counter with Output Register (multiplexed 3-state outputs)

The TC74HC697A is high speed CMOS UP/DOWN COUNTERS fabricated with silicon gate C²MOS technology.

It achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

It counts on the rising edge of the Counter Clock (CCK) input when "counter mode" is selected. If the up/down (U/ \overline{D}) input is held high, the internal counter counts up. Conversely, if U/ \overline{D} is held low, it counts down.

The internal counters outputs are latched into the output registers on the rising edge of the Register Clock (RCK) input.

The outputs (QA~QD) are selected as either internal counter or registered outputs by the output select (R/ \overline{C}) input. When high, the outputs are counter outputs and when low, they are registered outputs.

Two enable (\overline{ENP} , \overline{ENT}) inputs and a carry (\overline{RCO}) output are provided to enable cascading of the counters.

This facilitates easy implementation of n-bit counters without using external gates.

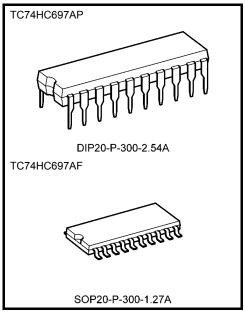
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 38 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Symmetrical output impedance:

$$\begin{split} |~I_{OH}~| &= I_{OL} = 6~mA~(min)~for~QA{\sim}QD \\ |~I_{OH}~| &= I_{OL} = 4~mA~(min)~for~~\overline{RCO} \end{split}$$

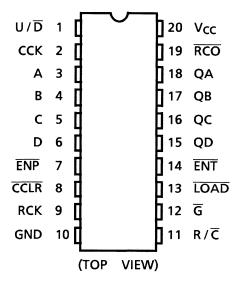
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS697



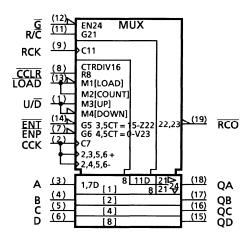
Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

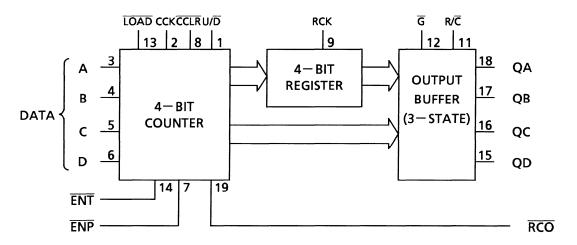
Pin Assignment



IEC Logic symbol



Block Diagram



Truth Table

Inputs							Outputs				Function			
CCLR	LOAD	ENP	ENT	CCK	U/D	RCK	R/C	G	QA	QB QC QD		i dilettori		
Х	Х	Х	Х	Х	Х	Х	Х	Н	Z	Z	Z	Z	Z	
L	Х	Х	Х	Х	Х	Х	L	L	L	L	L	L	Clear Counter	
Н	L	Х	Х		Х	Х	L	L	а	b	С	d	Load Counter	
Н	Η	Н	Х		Х	Х	L	L		No Cl		No Count		
Н	Η	Х	Н		Х	Х	L	L		NO CI	larige		NO COUNT	
Н	Н	L	L		Н	Х	L	L		Cou	nt Up		Count	
Н	Н	L	L		L	Х	L	L		Count	Down		Count	
Н	Х	Х	Х	\neg	Х	Х	L	L		No Cl	No Count			
Х	Х	Х	Х	Х	Х		Н	L	a' b' c' d'		Load Register			
Х	Х	Х	Х	Х	Х		Н	L	No Change				No Count	

X: Don't care

Z: High impedance

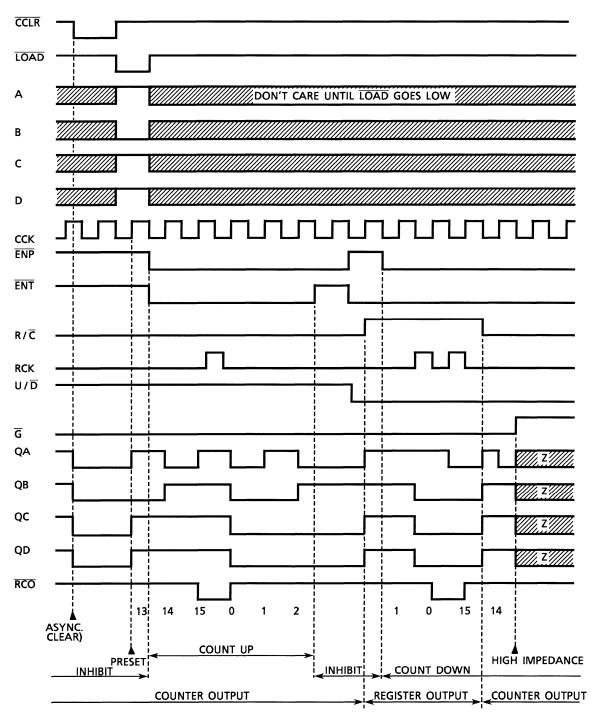
a~d: The level of steady state inputs at inputs A through D respectively.

a'~d': The level of steady state outputs at internal counter outputs QA' through QD' respectively.

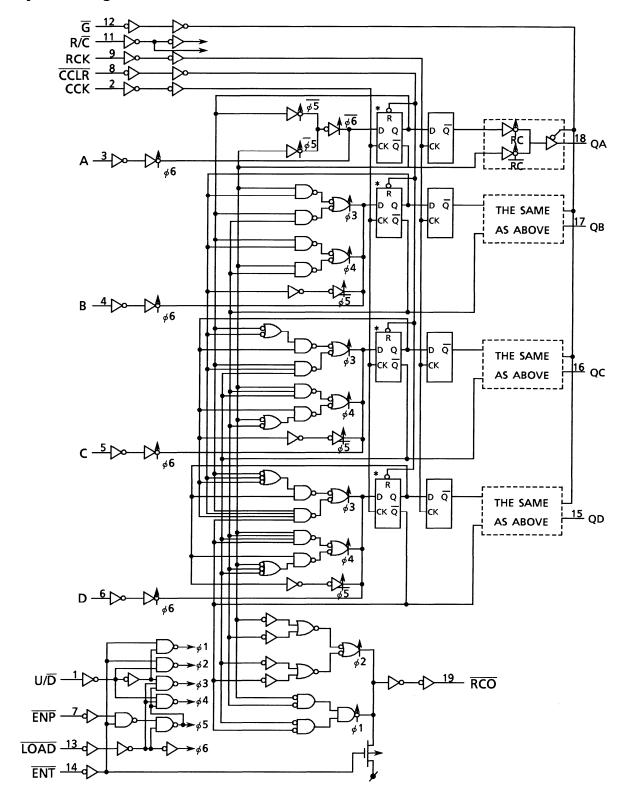
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 $\overline{\mathsf{RCO}} = (\overline{\mathsf{UP} \cdot \mathsf{QA} \cdot \mathsf{QB} \cdot \mathsf{QC} \cdot \mathsf{QD} \cdot \mathsf{ENT} + \overline{\mathsf{UP}} \cdot \overline{\mathsf{QA}} \cdot \overline{\mathsf{QB}} \cdot \overline{\mathsf{QC}} \cdot \overline{\mathsf{QD}} \cdot \mathsf{ENT}})$

Timing Chart



System Diagram



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2007-10-01

Absolute Maximum Ratings (Note 1)

Characteristic	es	Symbol	Rating	Unit
Supply voltage range		V_{CC}	-0.5~7	V
DC input voltage		V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage		V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current		I _{IK}	±20	mA
Output diode current		lok	±20	mA
DC output current	(RCO)	lou -	±25	mA
DC output current	(QA~QD)	Гоит	±35	IIIA
DC V _{CC} /ground current		Icc	±75	mA
Power dissipation		P _D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature		T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0~500 (V _{CC} = 4.5 V)	ns
		0~400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

	Test Condition			V _{CC}	-	Га = 25°(Ta = -4			
Characteristics	Symbol					Min	Тур.	Max	Min	Max	Unit
					2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}		_			3.15	_	_	3.15	_	V
					6.0	4.20	—	_	4.20	_	
					2.0	_	_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_			4.5	_	_	1.35	_	1.35	V
					6.0	_	_	1.80	_	1.80	
					2.0	1.9	2.0	_	1.9	_	
		V _{IN} = V _{IH}	or V _{IL}	$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
	V _{OH}				6.0	5.9	6.0	_	5.9	_	
High-level output voltage			RCO	$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	V
			RCO	$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
			QA~QD	$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	
				$I_{OH} = -7.8 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
					2.0	_	0.0	0.1	_	0.1	
		V _{IN} = V _{IH}	or VII	$I_{OL} = 20 \ \mu A$	4.5	_	0.0	0.1	_	0.1	
					6.0	_	0.0	0.1	_	0.1	
Low-level output voltage	V_{OL}		RCO	I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	V
			KCO	I _{OL} = 5.2 mA	6.0	_	0.18	0.26	_	0.33	
			QA~QD	I _{OL} = 6 mA	4.5	_	0.17	0.26	_	0.33	
			QATQD	$I_{OL} = 7.8 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
3-state output off-state current	I _{OZ}		V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	_	_	±0.5	_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} =	V _{IN} = V _{CC} or GND			_	_	±0.1	_	±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} =	V _{CC} or G	ND	6.0	_	_	4.0	_	40.0	μА



Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Test Condition				Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	4		2.0	_	75	95	
(CCK, RCK)	t _{W (L)}	_	4.5	_	15	19	ns
(CCN, RCN)	t _{W (H)}		6.0	_	13	16	
Minimovana navlana assialth			2.0	_	75	95	
Minimum pulse width	t _{W (L)}	_	4.5	_	15	19	ns
(CCLR)			6.0	_	13	16	
Minimum and the time			2.0	_	150	190	
Minimum set-up time (LOAD , ENT , ENP)	ts	_	4.5	_	30	38	ns
(LOAD, ENT, ENP)			6.0	_	13	32	
Minimum and the time			2.0	_	50	65	
Minimum set-up time	t _s	_	4.5	_	10	13	ns
(A, B, C, D)			6.0	_	9	11	
NA!			2.0	_	100	125	
Minimum set-up time (U/\overline{D})	ts	_	4.5	_	20	25	ns
(0/0)			6.0	_	17	21	
Minimum and the time			2.0	_	100	125	
Minimum set-up time	ts	_	4.5	_	20	25	ns
(CCK-RCK)			6.0	_	17	21	
Minimo una la alal tima a			2.0	_	5	5	
Minimum hold time	t _h	_	4.5	_	5	5	ns
(A, B, C, D)			6.0	_	5	5	
			2.0	_	0	0	
Minimum hold time	t _h	_	4.5	_	0	0	ns
			6.0	_	0	0	
			2.0	_	5	5	
Minimum removal time	t _{rem}	_	4.5	_	5	5	ns
			6.0	_	5	5	
			2.0	_	5	4	
Clock frequency	f	_	4.5	_	25	20	MHz
			6.0	_	29	24	

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}\text{C}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time (\overline{RCO})	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time (CCK- RCO)	t _{pLH}	_	_	24	41	ns
Propagation delay time (ENT- RCO)	t _{pLH}	_	_	13	23	ns
Propagation delay time (CCLR - RCO)	t _{pLH}	_	_	23	38	ns
Maximum clock frequency	f _{max}		25	38	_	MHz



AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition			-	Ta = 25°0		Ta = -4	Unit	
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
Output transition time	t _{TLH}			2.0	_	25	60	_	75	
(Qn)		_	50	4.5	_	7	12	_	15	ns
(011)	t _{THL}			6.0	_	6	10	_	13	
Output transition time	4			2.0	_	30	75	_	95	
(RCO)	t _{pLH}	_	50	4.5	_	8	15	_	19	ns
(RCO)	t _{pHL}			6.0	_	7	13	_	16	
				2.0	_	90	195	_	245	
			50	4.5	_	26	39	_	49	
Propagation delay time	t_{pLH}			6.0	_	19	33	_	42	no
(CCK-Q)	t_{pHL}	_		2.0	_	103	235	_	295	ns
(150	4.5	_	31	47	_	59	
				6.0	_	23	40	_	50	
				2.0	_	82	180	_	225	
			50	4.5	_	24	36	_	45	
Propagation delay time	t_{pLH}			6.0	_	18	31	_	38	
(RCK-Q)	t_{pHL}	_		2.0	_	95	220	_	275	ns
(1.13.1. 4)			150	4.5	_	29	44	_	55	
				6.0	_	22	37	_	47	
				2.0	_	60	145	_	180	
			50	4.5	_	19	29	_	36	
Propagation delay time	t_{pLH}			6.0	_	14	25	_	31	
(R/C-Q)	t _{pHL}	_		2.0	_	73	185	_	230	ns
(122 4)			150	4.5	_	24	37	_	46	
				6.0	_	18	31	_	39	
				2.0	_	89	195	_	245	
			50	4.5	_	26	39	_	49	
Propagation delay time				6.0	_	20	33	_	42	no
(CCLR -Q)	t _{pHL}	_		2.0	_	102	235	_	295	ns
(150	4.5	_	31	47	_	59	
				6.0	_	24	40	_	50	
Propagation delay	4			2.0	_	108	235	_	295	
time	t _{pLH}	_	50	4.5	_	31	47	_	59	ns
(CCK-RCO)	t _{pHL}			6.0	_	23	40	_	50	
Propagation delay	4			2.0	_	63	135	_	170	
time	t _{pLH}	_	50	4.5	_	18	27	_	34	ns
(ENT - RCO)	t _{pHL}			6.0	_	14	23	_	29	
Propagation delay				2.0	_	98	220	_	275	
time	t _{pLH}	_	50	4.5	_	29	44	_	55	ns
(CCLR - RCO)	•			6.0	_	23	37	_	47	

		Test Condition			-	Ta = 25°C)	Ta = -4		
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Min Max - 145 - 29 - 25 - 195 - 39 - 33 - 145 - 29 - 25 4 - 20 24 - 10 - 10	Unit
				2.0	_	45	115	_	145	
			50	4.5	_	15	23	_	29	
Output enable time	t_{pZL}	R _L = 1 kΩ		6.0	_	12	20	_	25	ns
(G -Q)	t _{pZH}			2.0	_	58	155	_	195	113
			150	4.5	_	20	31	_	39	
				6.0	_	16	26	_	33	
Output disable time				2.0	_	32	115	_	145	
Output disable time $(\overline{G} - Q)$	t _{pLZ}	$R_L = 1 \text{ k}\Omega$	50	4.5	_	17	23	_	29	ns
(G -Q)	t _{pHZ}			6.0	_	14	20	_	25	
				2.0	5	11	_	4	_	
Maximum clock frequency	f _{max}	_	50	4.5	25	38	_	20	_	MHz
,				6.0	29	52	_	24	_	
Input capacitance	C _{IN}	_			_	5	10	_	10	pF
Output capacitance	C _{OUT}	_			_	13	_	_	_	pF
Power dissipation	C _{PD}					72				nE.
capacitance	(Note)	_			_	12	_	_	_	pF

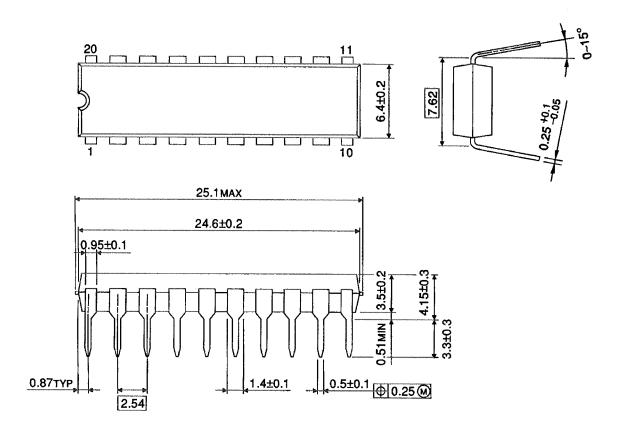
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC} \; (opr) = C_{PD} \! \cdot \! V_{CC} \! \cdot \! f_{IN} + I_{CC}$$

Package Dimensions

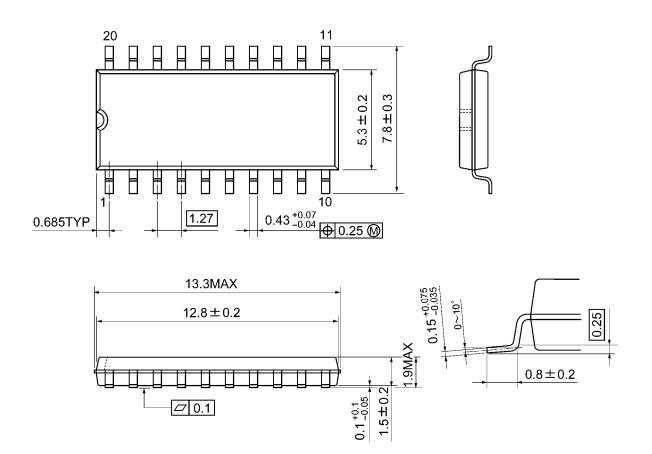
DIP20-P-300-2.54A Unit: mm



Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

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